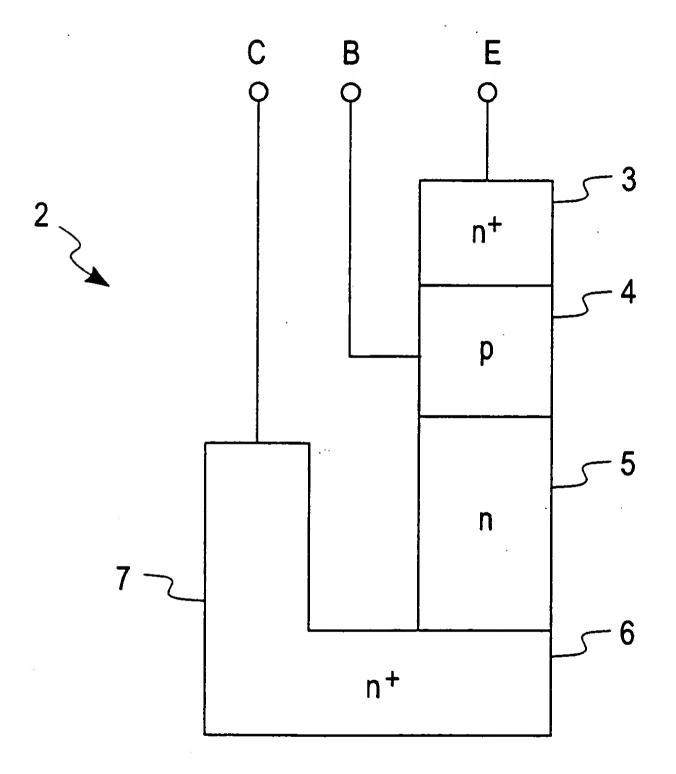
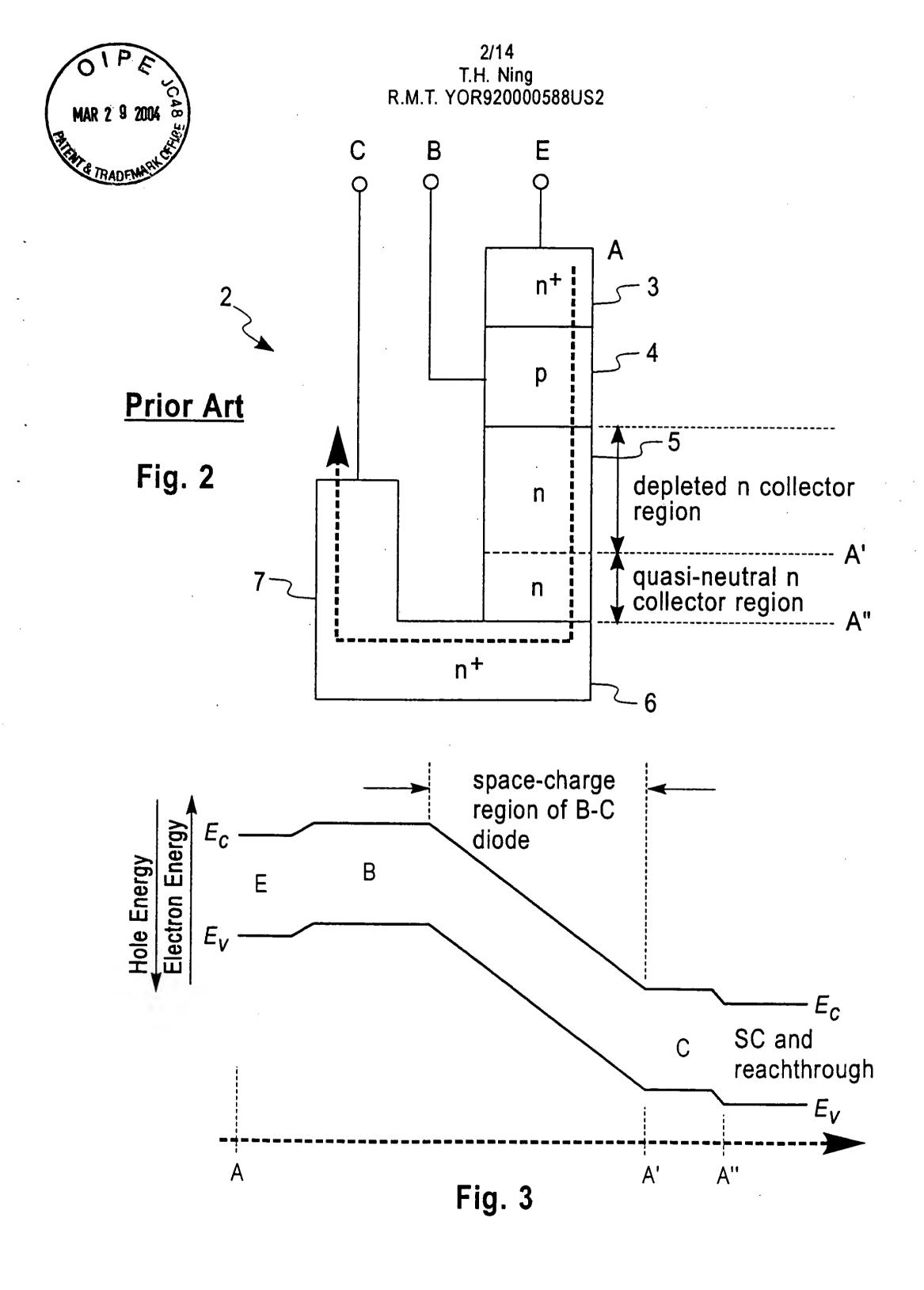
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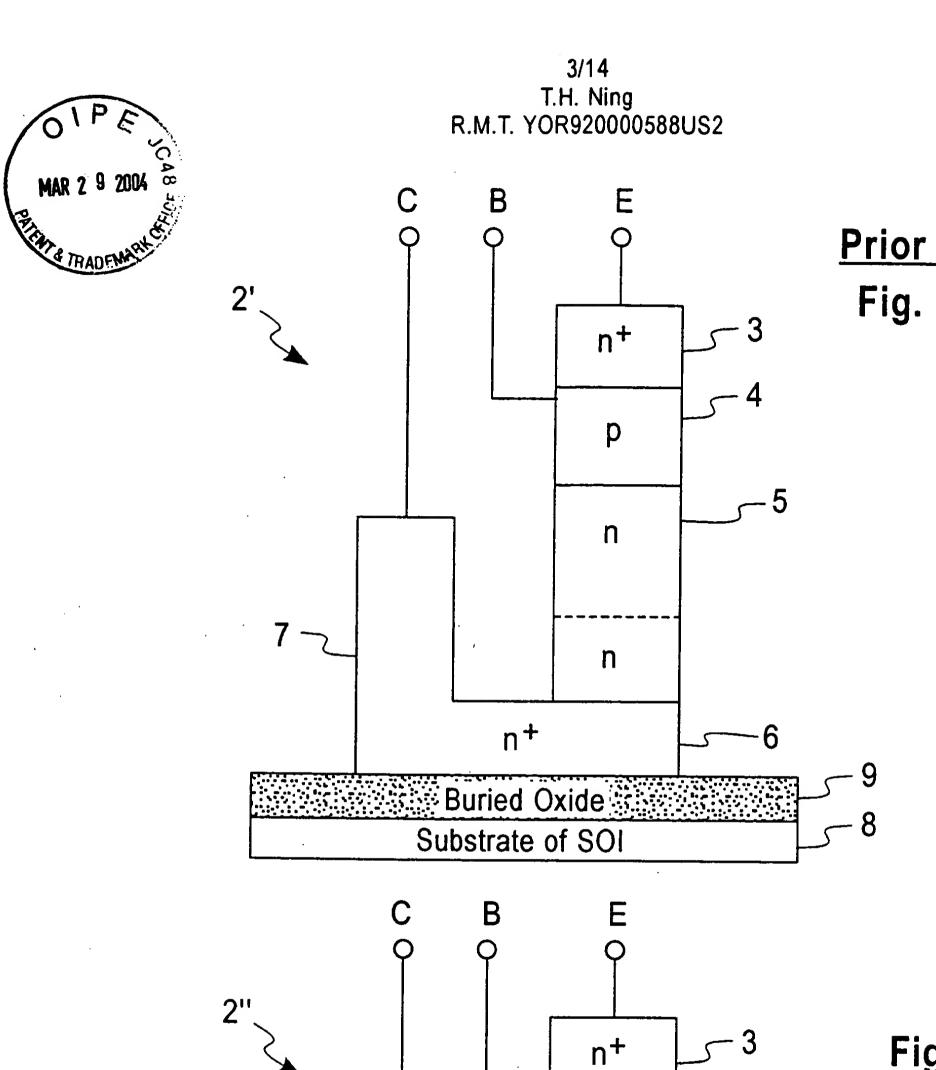


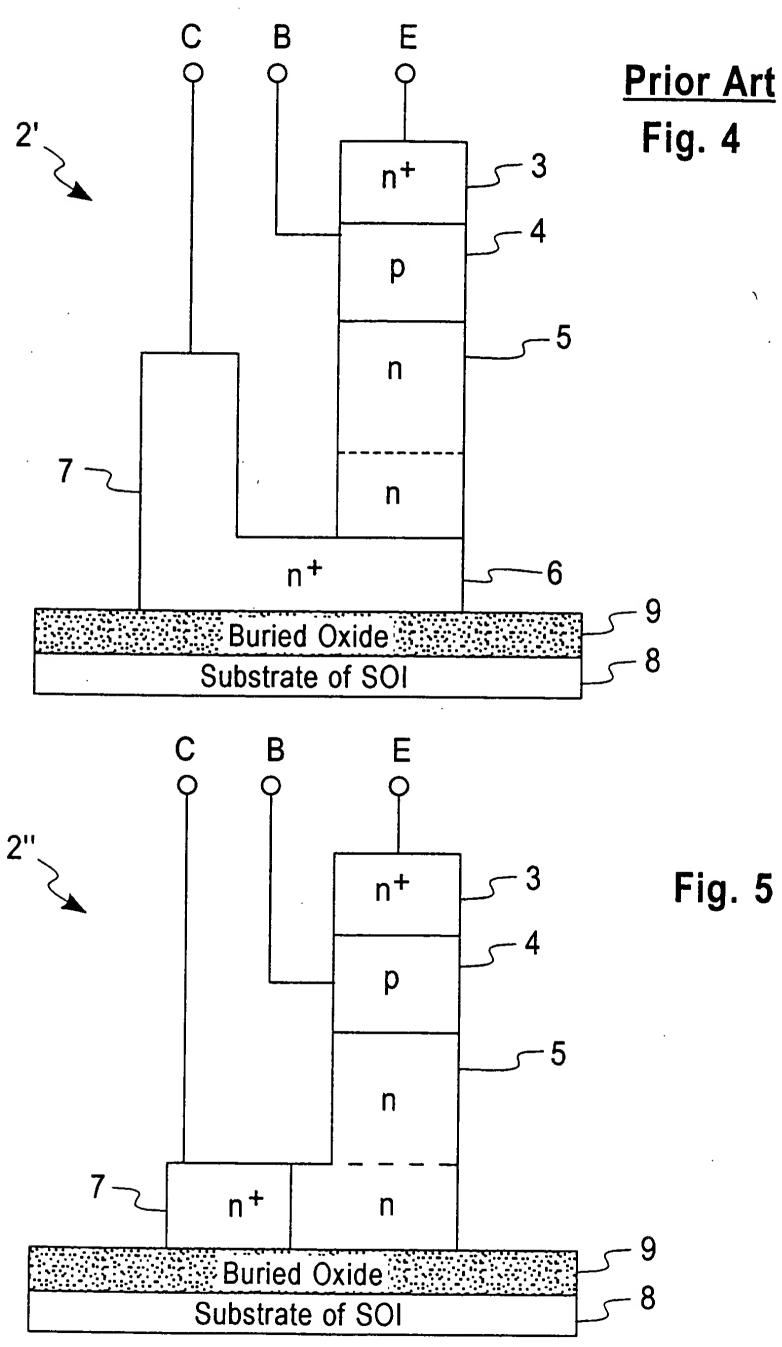


Prior Art

Fig.1









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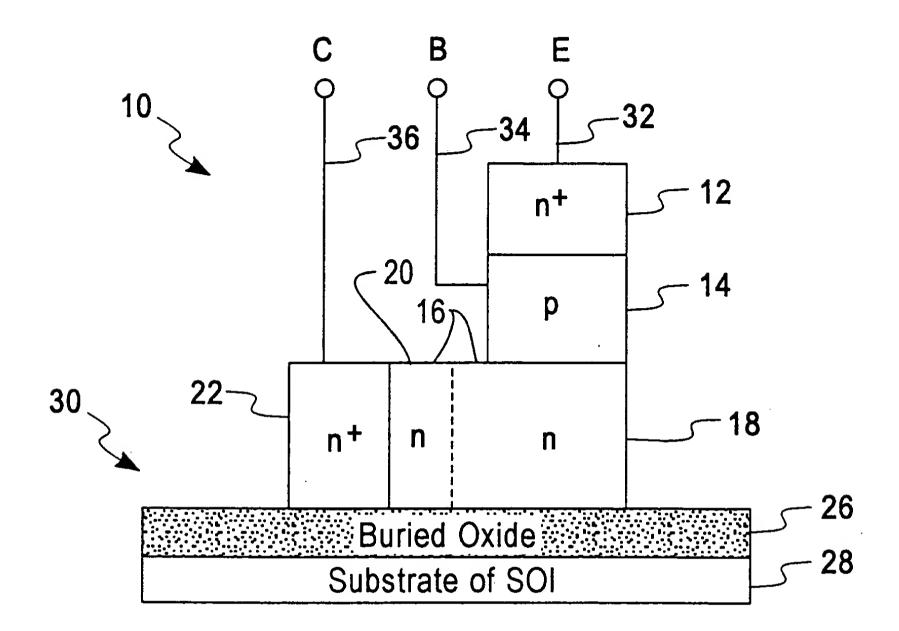


Fig. 6

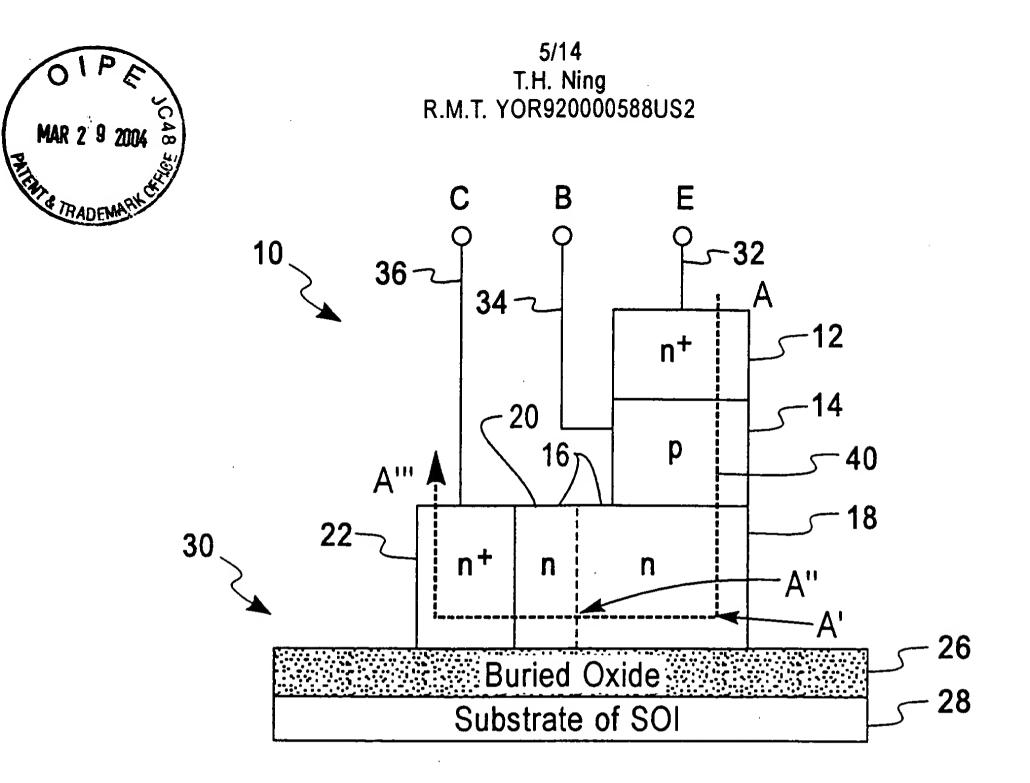
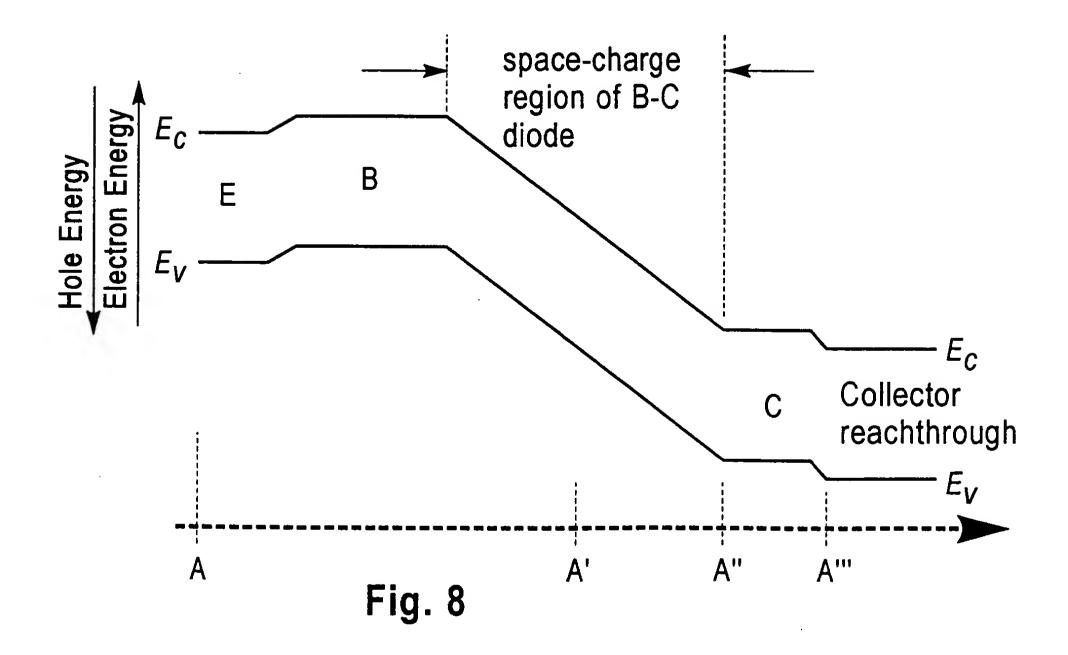


Fig. 7





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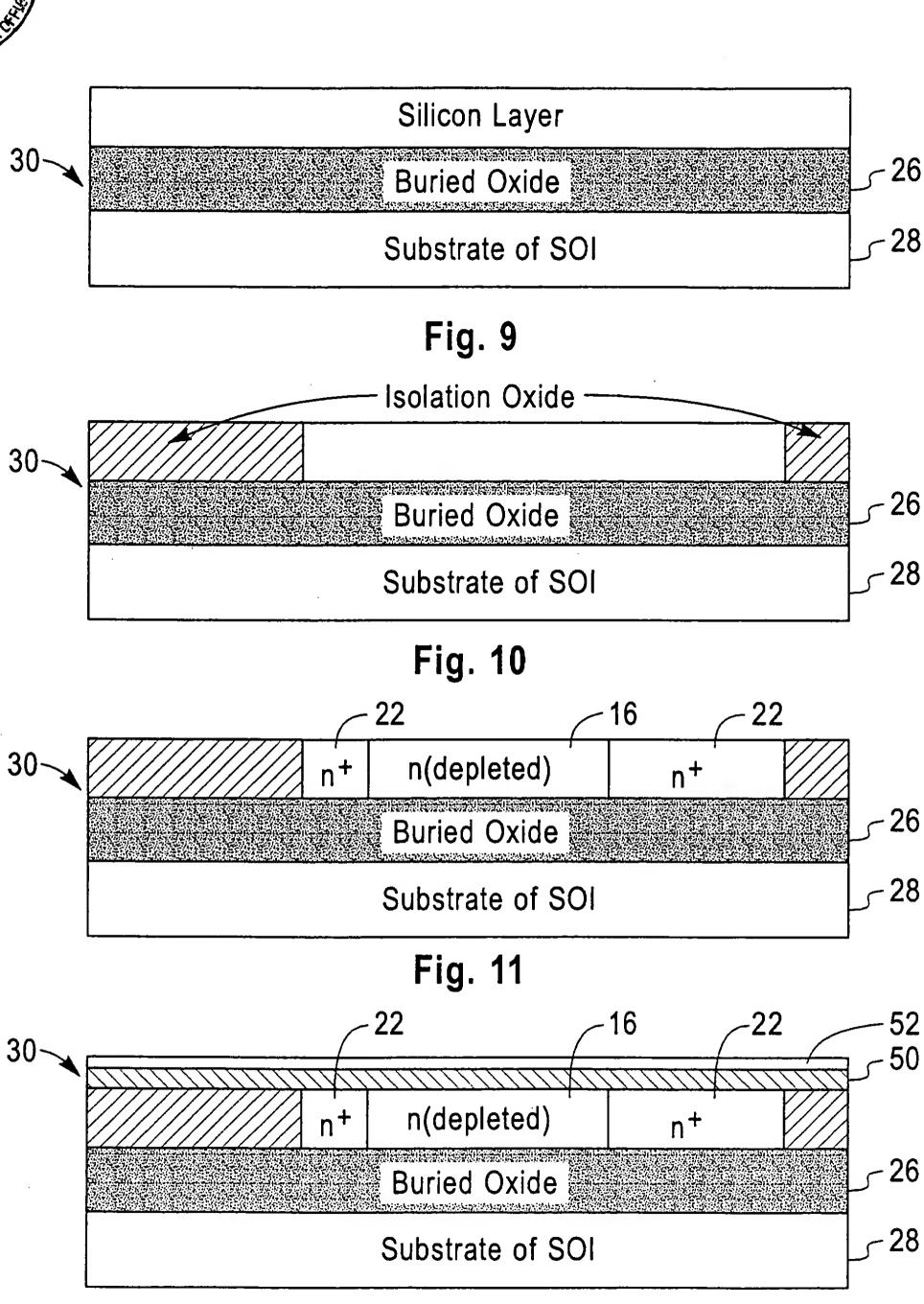


Fig. 12



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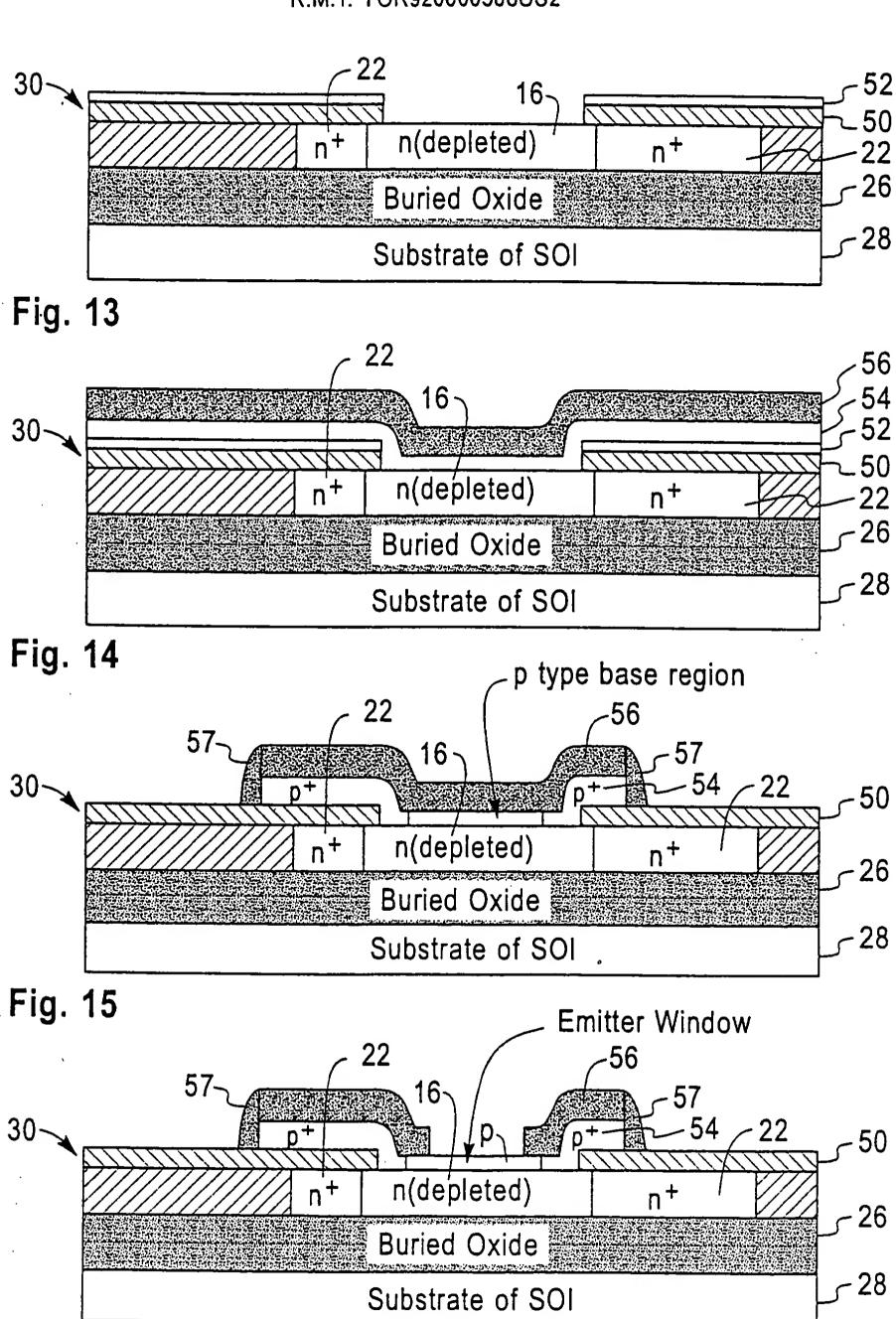
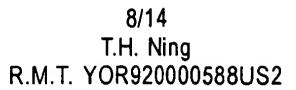


Fig. 16





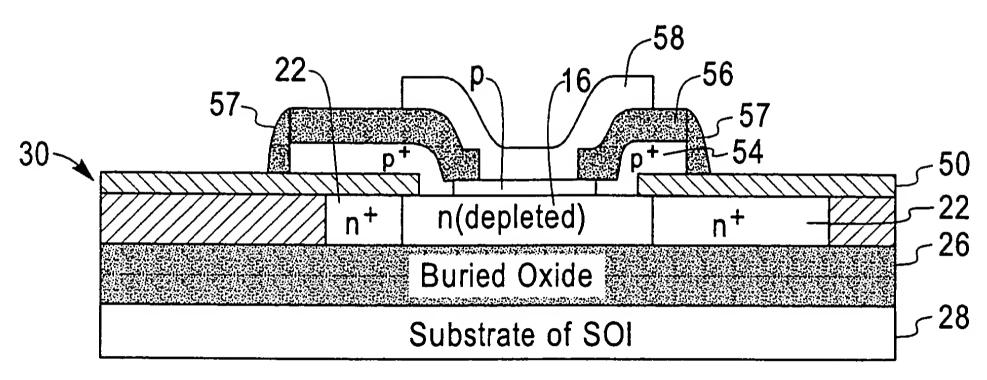


Fig. 17

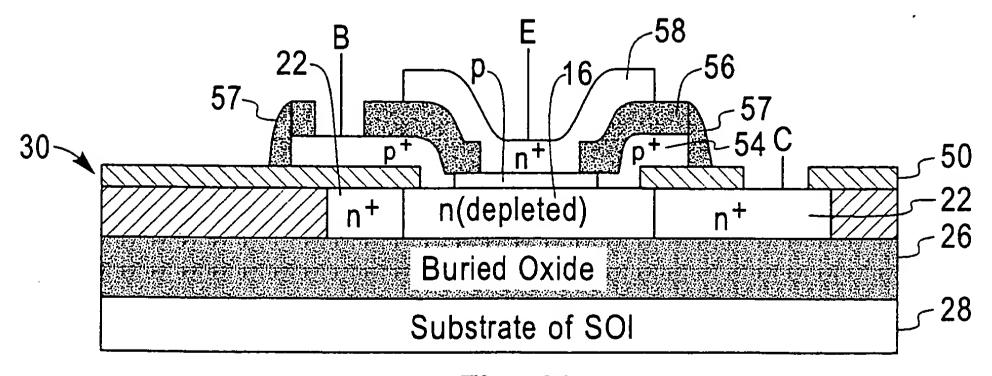


Fig. 18

9/14 T.H. Ning R.M.T. YOR920000588US2 MAR 2 9 2004 & RADEMARY. p+ polisilcon Base window Emitter window - n+ polysilicon 58 54 16 18 18 E

Fig. 19

Isolation oxide -

Base contact opening

Collector contact opening

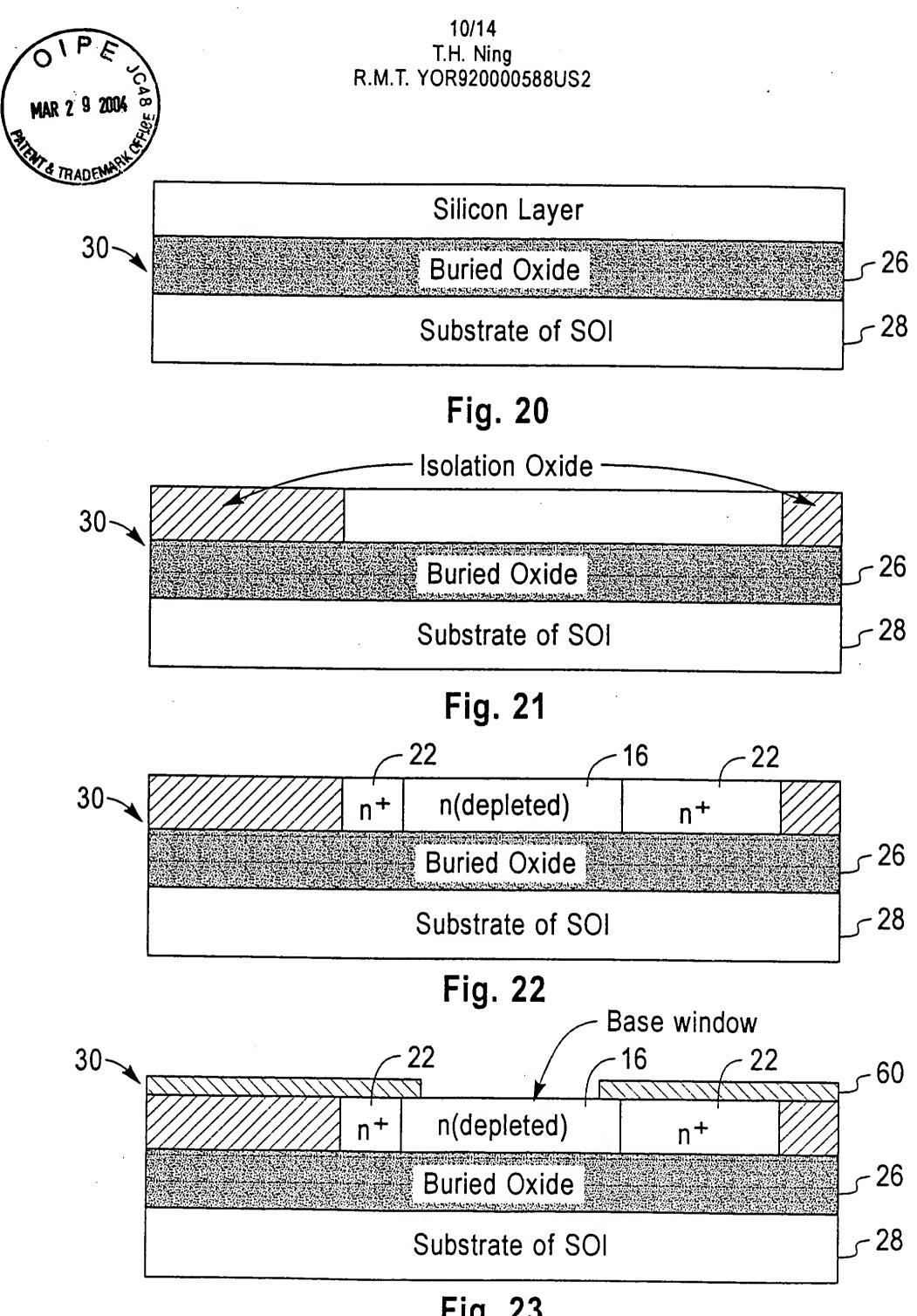
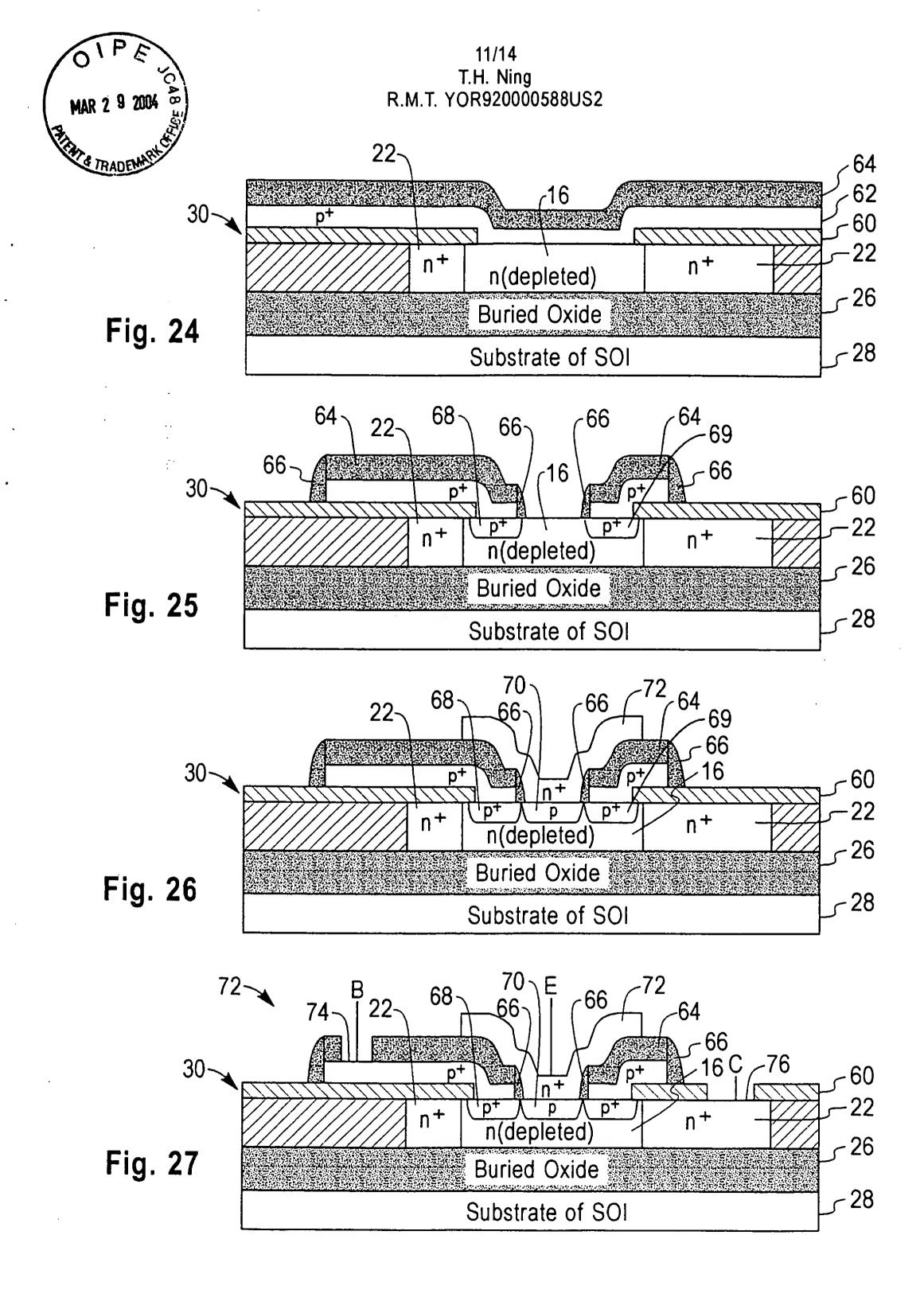


Fig. 23





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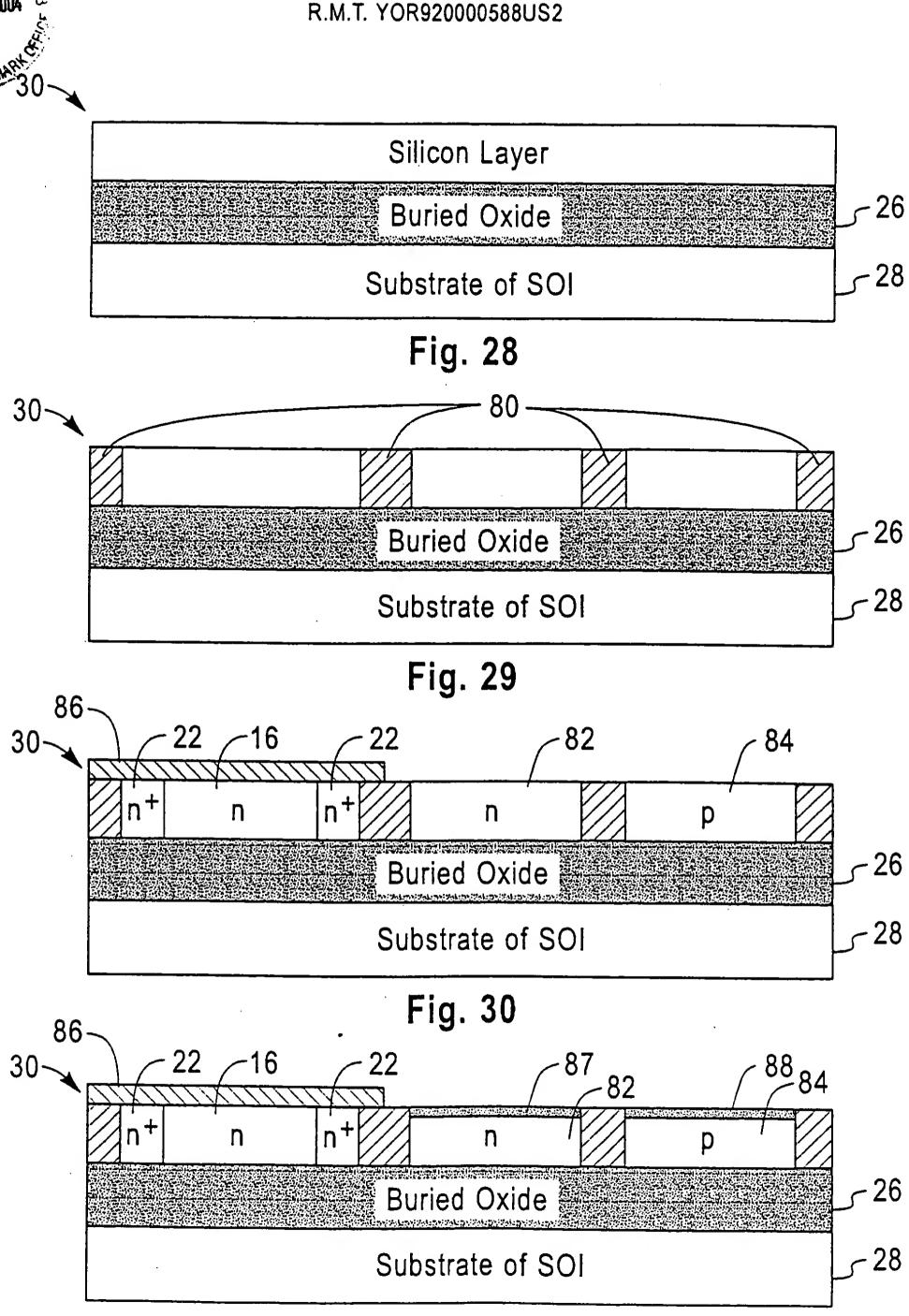


Fig. 31

